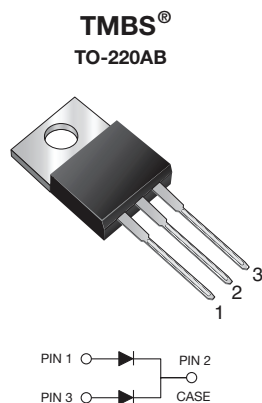


# Dual High Voltage Trench MOS Barrier Schottky Rectifier

Ultra Low  $V_F = 0.41\text{ V}$  at  $I_F = 5\text{ A}$



## FEATURES

- Trench MOS Schottky technology
- Low forward voltage drop, low power losses
- High efficiency operation
- Solder bath temperature 275 °C maximum, 10 s, per JESD 22-B106
- Material categorization: for definitions of compliance please see [www.vishay.com/doc?99912](http://www.vishay.com/doc?99912)



**RoHS**  
COMPLIANT  
HALOGEN  
**FREE**

## TYPICAL APPLICATIONS

For use in high frequency converters, switching power supplies, freewheeling diodes, OR-ing diode, DC/DC converters, and reverse battery protection.

## PRIMARY CHARACTERISTICS

|                                       |                |
|---------------------------------------|----------------|
| $I_{F(AV)}$                           | 2 x 20 A       |
| $V_{RRM}$                             | 120 V          |
| $I_{FSM}$                             | 250 A          |
| $V_F$ at $I_F = 20\text{ A}$ (125 °C) | 0.62 V         |
| $T_J$ max.                            | 150 °C         |
| Package                               | TO-220AB       |
| Diode variation                       | Common cathode |

## MECHANICAL DATA

**Case:** TO-220AB

Molding compound meets UL 94 V-0 flammability rating  
Base P/N-M3 - halogen-free, RoHS-compliant, and commercial grade

**Terminals:** matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

M3 suffix meets JESD 201 class 1A whisker test

**Polarity:** as marked

**Mounting Torque:** 10 in-lbs maximum

## MAXIMUM RATINGS ( $T_A = 25\text{ °C}$ unless otherwise noted)

| PARAMETER  | SYMBOL      | V40120CI    | UNIT |
|--|-------------|-------------|------|
| Maximum repetitive peak reverse voltage  | $V_{RRM}$   | 120         | V    |
| Maximum average forward rectified current (fig. 1)   | $I_{F(AV)}$ | 40          | A    |
| per device   |             | 20          |      |
| per diode  |             |             |      |
| Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode | $I_{FSM}$   | 250         | A    |
| Operating junction temperature range   | $T_J$ (1)   | -40 to +150 | °C   |
| Storage temperature range  | $T_{STG}$   | -55 to +150 |      |

### Note

(1) The heat generated must be less than the thermal conductivity from junction to ambient:  $dP_D/dT_J < 1/R_{\theta JA}$

**ELECTRICAL CHARACTERISTICS** ( $T_A = 25\text{ }^{\circ}\text{C}$  unless otherwise noted)

| PARAMETER                               | TEST CONDITIONS        |                         | SYMBOL                        | TYP. | MAX. | UNIT |
|---|------------------------|-------------------------|-------------------------------|------|------|------|
| Instantaneous forward voltage per diode | I <sub>F</sub> = 5 A   | T <sub>A</sub> = 25 °C  | V <sub>F</sub> <sup>(1)</sup> | 0.48 | -    | V    |
|   | I <sub>F</sub> = 10 A  |                         |                               | 0.57 | -    |      |
|   | I <sub>F</sub> = 20 A  |                         |                               | 0.74 | 0.82 |      |
|   | I <sub>F</sub> = 5 A   | T <sub>A</sub> = 125 °C |                               | 0.41 | -    |      |
|   | I <sub>F</sub> = 10 A  |                         |                               | 0.52 | -    |      |
|   | I <sub>F</sub> = 20 A  |                         |                               | 0.62 | 0.70 |      |
| Reverse current per diode               | V <sub>R</sub> = 90 V  | T <sub>A</sub> = 25 °C  | I <sub>R</sub> <sup>(2)</sup> | 0.01 | -    | mA   |
|   |                        | T <sub>A</sub> = 125 °C |                               | 9.0  | -    |      |
|   | V <sub>R</sub> = 120 V | T <sub>A</sub> = 25 °C  |                               | -    | 0.7  |      |
|   |                        | T <sub>A</sub> = 125 °C |                               | 20.0 | 38   |      |
| Junction capacitance                    | 4 V, 1MHz              |                         | C <sub>J</sub>                | 2400 | -    | pF   |

**Notes**(1) Pulse test: 300  $\mu\text{s}$  pulse width, 1 % duty cycle(2) Pulse test: Pulse width  $\leq 5\text{ ms}$ **THERMAL CHARACTERISTICS** ( $T_A = 25\text{ }^{\circ}\text{C}$  unless otherwise noted)

| PARAMETER                             | SYMBOL          | V40120CI | UNIT                 |
|---------------------------------------|-----------------|----------|----------------------|
| Typical thermal resistance per device | $R_{\theta JC}$ | 1.7      | $^{\circ}\text{C/W}$ |

**ORDERING INFORMATION** (Example)

| PREFERRED P/N | UNIT WEIGHT (g) | PACKAGE CODE | BASE QUANTITY | DELIVERY MODE |
|---------------|-----------------|--------------|---------------|---------------|
| V40120CI-M3/P | 1.88            | P            | 50/tube       | Tube          |

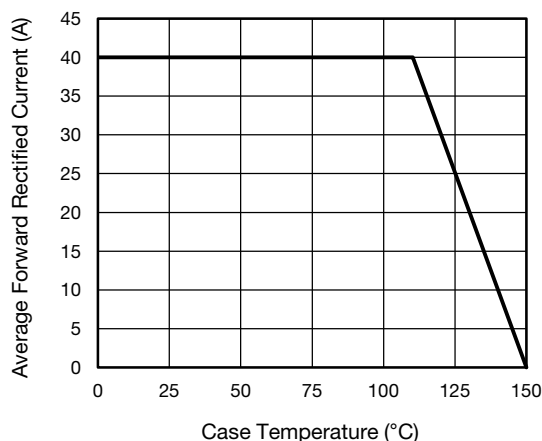
**RATINGS AND CHARACTERISTICS CURVES** ( $T_A = 25\text{ }^{\circ}\text{C}$  unless otherwise noted)


Fig. 1 - Forward Current Derating Curve

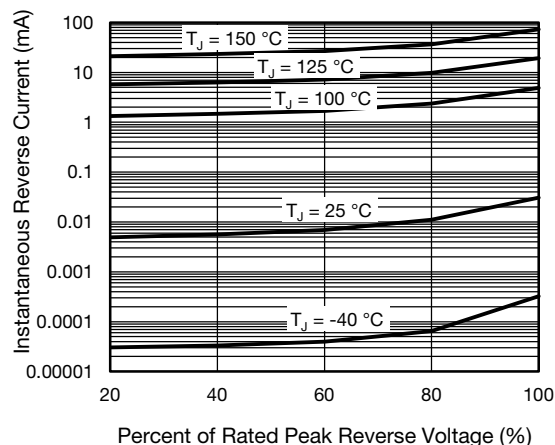


Fig. 4 - Typical Reverse Characteristics Per Diode

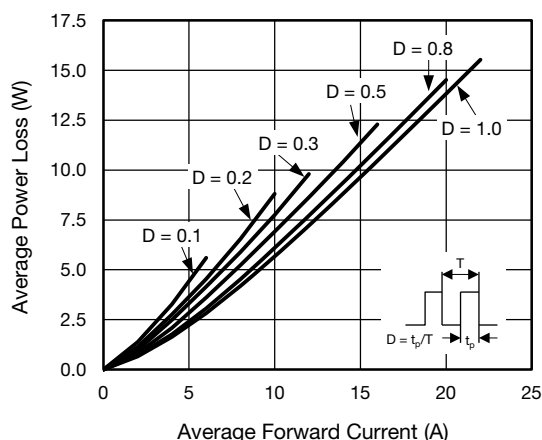


Fig. 2 - Forward Power Loss Characteristics Per Diode

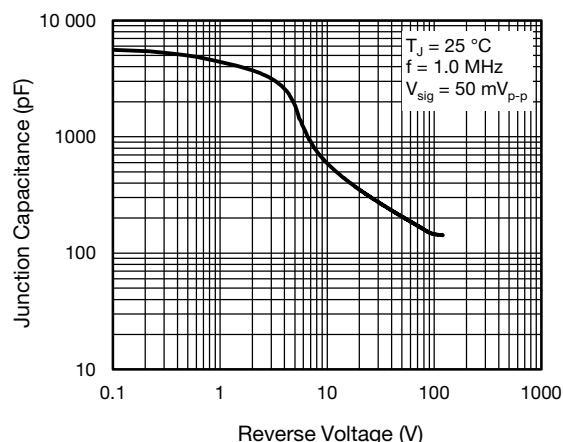


Fig. 5 - Typical Junction Capacitance

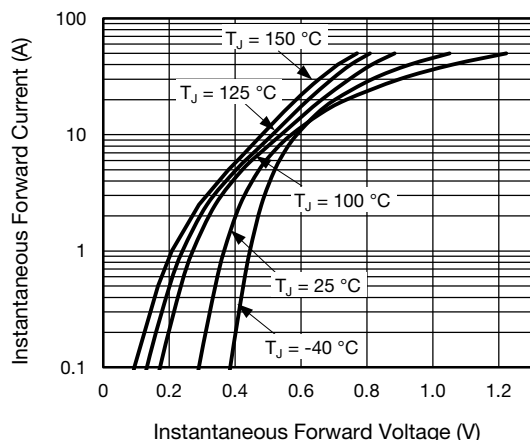


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

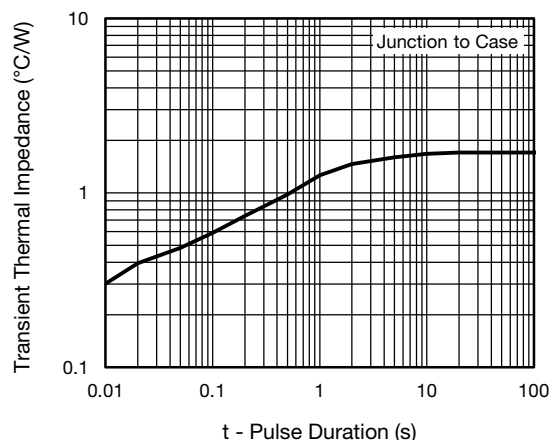
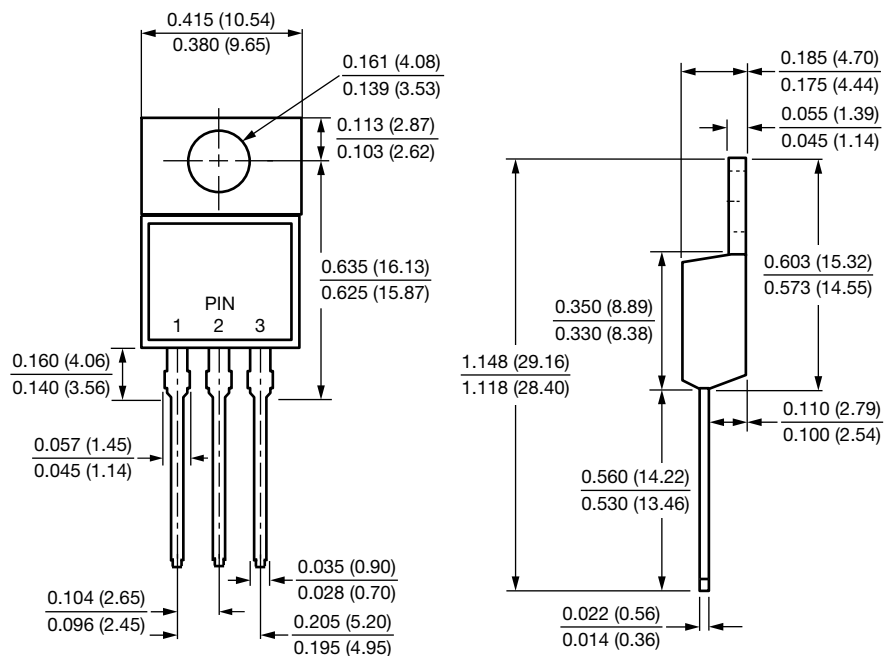


Fig. 6 - Typical Transient Thermal Impedance Per Device



PACKAGE OUTLINE DIMENSIONS in inches (millimeters)

TO-220AB





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